

# LTC3526L-2/LTC3526LB-2

550mA 2MHz Synchronous Step-Up DC/DC Converters in 2mm × 2mm DFN

### FEATURES

- Delivers 3.3V at 100mA from a Single Alkaline/ NiMH Cell or 3.3V at 200mA from Two Cells
- V<sub>IN</sub> Start-Up Voltage: 680mV
- 1.5V to 5.25V V<sub>OUT</sub> Range
- Up to 94% Efficiency
- Output Disconnect
- 2MHz Fixed Frequency Operation
- V<sub>IN</sub> > V<sub>OUT</sub> Operation
- Integrated Soft-Start
- Current Mode Control with Internal Compensation
- Burst Mode<sup>®</sup> Operation with 9μA I<sub>Ω</sub> (LTC3526L-2)
- Low Noise PWM Operation (LTC3526LB-2)
- Internal Synchronous Rectifier
- Logic Controlled Shutdown (I<sub>Q</sub> < 1µA)</p>
- Anti-Ring Control
- Low Profile (2mm × 2mm × 0.75mm) 6-Lead DFN Package

### **APPLICATIONS**

- Medical Instruments
- Noise Canceling Headphones

TYPICAL APPLICATION

- Wireless Mice
- Bluetooth Headsets

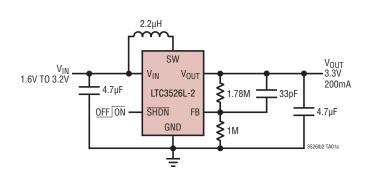
# DESCRIPTION

The LTC®3526L-2/LTC3526LB-2 are synchronous, fixed frequency step-up DC/DC converters with output disconnect. Synchronous rectification enables high efficiency in the low profile  $2mm \times 2mm$  DFN package. Battery life in single AA/AAA powered products is extended further with a 680mV start-up voltage and operation down to 500mV once started.

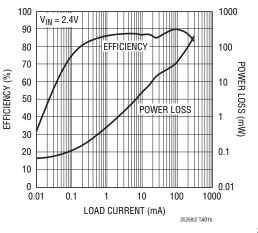
A switching frequency of 2MHz minimizes solution footprint by allowing the use of tiny, low profile inductors and ceramic capacitors. The current mode PWM design is internally compensated, reducing external parts count. The LTC3526L-2 features Burst Mode operation at light load conditions allowing it to maintain high efficiency over a wide range of load. The LTC3526LB-2 features fixed frequency operation for low noise applications. Anti-ring circuitry reduces EMI by damping the inductor in discontinuous mode. Additional features include a low shutdown current of under 1 $\mu$ A and thermal shutdown.

The LTC3526L-2/LTC3526LB-2 are housed in a 2mm  $\times$  2mm  $\times$  0.75mm DFN package.

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#### Efficiency and Power Loss vs Load Current

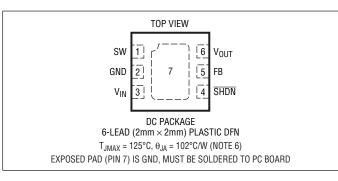




### ABSOLUTE MAXIMUM RATINGS

(Note 1)	
V <sub>IN</sub> Voltage	0.3V to 6V
SW Voltage	
DC	0.3V to 6V
Pulsed <100ns	0.3V to 7V
SHDN, FB Voltage	0.3V to 6V
V <sub>OUT</sub>	0.3V to 6V
Operating Temperature Range	
(Notes 2, 5)	40°C to 85°C
Storage Temperature Range	65°C to 150°C

# PIN CONFIGURATION



### **ORDER INFORMATION**

LEAD FREE FINISH	TAPE AND REEL	PART MARKING	PACKAGE DESCRIPTION	TEMPERATURE RANGE
LTC3526LEDC-2#PBF	LTC3526LEDC-2#TRPBF	LFFC	6-Lead ( $2mm \times 2mm$ ) Plastic DFN	-40°C to 85°C
LTC3526LBEDC-2#PBF	LTC3526LBEDC-2#TRPBF	LFFD	6-Lead (2mm $\times$ 2mm) Plastic DFN	-40°C to 85°C

Consult LTC Marketing for parts specified with wider operating temperature ranges. Consult LTC Marketing for information on non-standard lead based finish parts.

For more information on lead free part marking, go to: http://www.linear.com/leadfree/ For more information on tape and reel specifications, go to: http://www.linear.com/tapeandreel/

# **ELECTRICAL CHARACTERISTICS** The $\bullet$ denotes the specifications which apply over the specified operating temperature range of -40°C to 85°C, otherwise specifications are at T<sub>A</sub> = 25°C. V<sub>IN</sub> = 1.2V, V<sub>OUT</sub> = 3.3V unless otherwise noted.

PARAMETER	CONDITIONS		MIN	ТҮР	MAX	UNITS
Minimum Start-Up Input Voltage	I <sub>LOAD</sub> = 1mA			0.68	0.8	V
Input Voltage Range	After Start-Up. (Minimum Voltage is Load Dependent)	•	0.5		5	V
Output Voltage Adjust Range		•	1.5		5.25	V
Feedback Pin Voltage		•	1.165	1.195	1.225	V
Feedback Pin Input Current	V <sub>FB</sub> = 1.30V			1	50	nA
Quiescent Current—Shutdown	$V_{\overline{SHDN}} = 0V$ , Not Including Switch Leakage, $V_{OUT} = 0V$			0.01	1	μA
Quiescent Current—Active	Measured on V <sub>OUT</sub> , Nonswitching			250	500	μA
Quiescent Current—Burst	Measured on V <sub>OUT</sub> , FB > 1.230V (LTC3526L-2 Only)			9	18	μA
N-Channel MOSFET Switch Leakage Current	V <sub>SW</sub> = 5V			0.1	5	μA
P-Channel MOSFET Switch Leakage Current	$V_{SW} = 5V, V_{OUT} = 0V$			0.1	10	μA
N-Channel MOSFET Switch On Resistance	V <sub>OUT</sub> = 3.3V			0.4		Ω
P-Channel MOSFET Switch On Resistance	V <sub>OUT</sub> = 3.3V			0.6		Ω
N-Channel MOSFET Current Limit		•	550	750		mA
Current Limit Delay to Output	(Note 3)			60		ns
Maximum Duty Cycle	V <sub>FB</sub> = 1.15V, V <sub>OUT</sub> = 5V	•	87	90		%
Minimum Duty Cycle	V <sub>FB</sub> = 1.3V	•			0	%
Switching Frequency		•	1.8	2	2.4	MHz
SHDN Pin Input High Voltage			0.8			V
SHDN Pin Input Low Voltage					0.3	V
						3526lb2fa



# **ELECTRICAL CHARACTERISTICS**

**Note 1:** Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. Exposure to any Absolute Maximum Rating condition for extended periods may affect device reliability and lifetime.

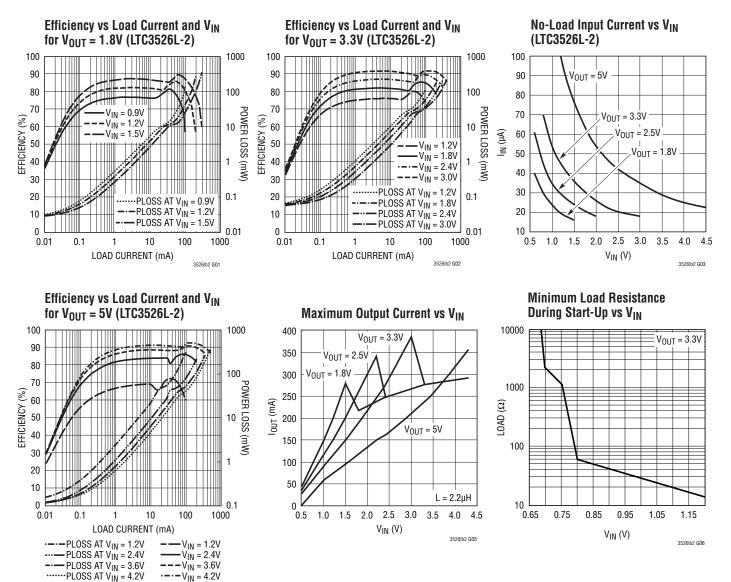
**Note 2:** The LTC3526LE-2/LTC3526LBE-2 are guaranteed to meet performance specifications from 0°C to 85°C. Specifications over -40°C to 85°C operating temperature range are assured by design, characterization and correlation with statistical process controls.

**Note 3:** Specification is guaranteed by design and not 100% tested in production.

**Note 4:** Current measurements are made when the output is not switching. **Note 5:** This IC includes overtemperature protection that is intended to protect the device during momentary overload conditions. Junction temperature will exceed 125°C when overtemperature protection is active. Continuous operation above the specified maximum operating junction temperature may result in device degradation or failure.

**Note 6:** Failure to solder the exposed backside of the package to the PC board ground plane will result in a thermal resistance much higher than 102°C/W.

### **TYPICAL PERFORMANCE CHARACTERISTICS** $T_A = 25^{\circ}C$ , unless otherwise noted.

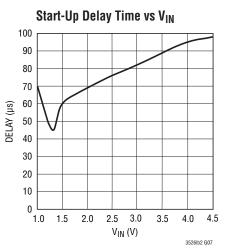


3526lb2fa

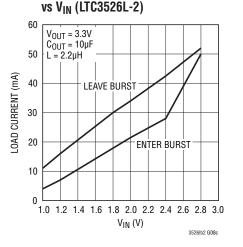


3526lb2 G04

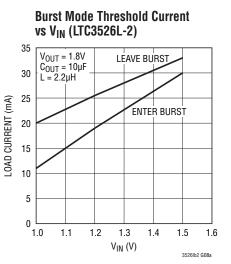
### TYPICAL PERFORMANCE CHARACTERISTICS $T_A = 25^{\circ}C$ , unless otherwise noted.



**Burst Mode Threshold Current** 



R<sub>DS(ON)</sub> vs V<sub>OUT</sub> 0.90 0.85 0.80 0.75 0.70 ପି 0.65 PMOS (NO) 0.60 SCI B 200 0.55 0.50 0.45 NMOS 0.40 0.35 0.30 1.5 2.0 2.5 3.0 3.5 4.0 4.5 5.0 V<sub>OUT</sub> (V) 3526lb2 G10



**Burst Mode Threshold Current** 

vs V<sub>IN</sub> (LTC3526L-2)

LEAVE BURST

V<sub>OUT</sub> = 5V C<sub>OUT</sub> = 10µF L = 2.2µH

70

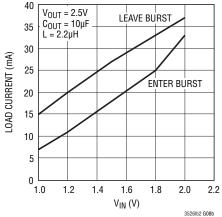
60

50

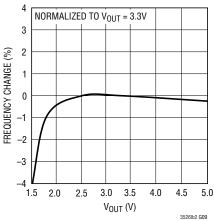
40

LOAD CURRENT (mA)

#### **Burst Mode Threshold Current** vs V<sub>IN</sub> (LTC3526L-2) V<sub>OUT</sub> = 2.5V



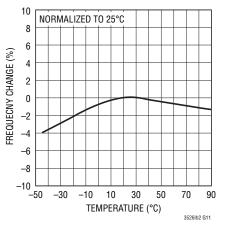
#### **Oscillator Frequency Change** vs V<sub>OUT</sub>



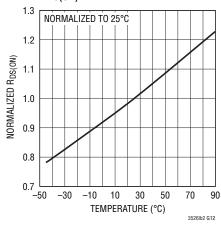
30 ENTER BURST 20 10 0 1.0 1.5 2.0 2.5 3.0 3.5 4.0 V<sub>IN</sub> (V) 3526lb2 G08c

4.5

**Oscillator Frequency Change** vs Temperature

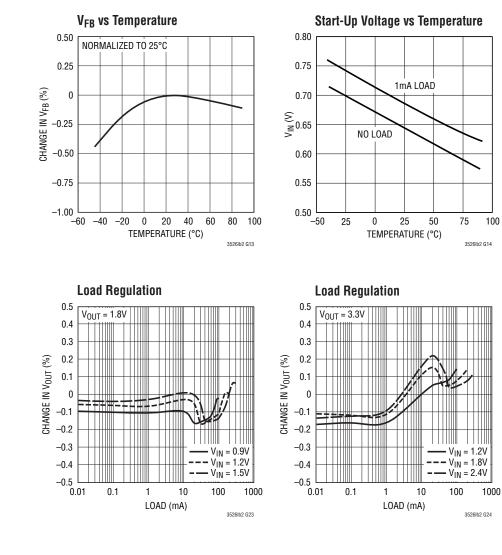


R<sub>DS(ON)</sub> Change vs Temperature

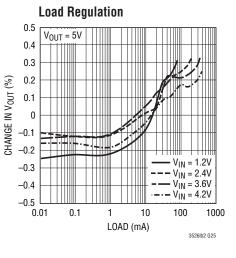


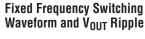


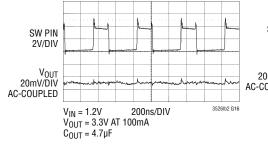
### TYPICAL PERFORMANCE CHARACTERISTICS $T_A = 25^{\circ}C$ , unless otherwise noted.

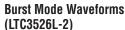


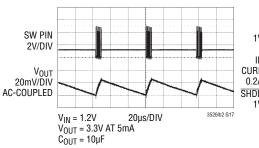
**Burst Mode Quiesent Current** vs V<sub>OUT</sub> (LTC3526L-2) 10.0 9.5 9.0 lg (µA) 8.5 8.0 7.5 7.0 1.5 2.0 2.5 3.0 3.5 4.0 4.5 5.0 VOUT (V) 3526lb2 G15



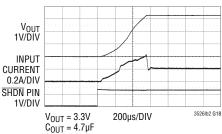






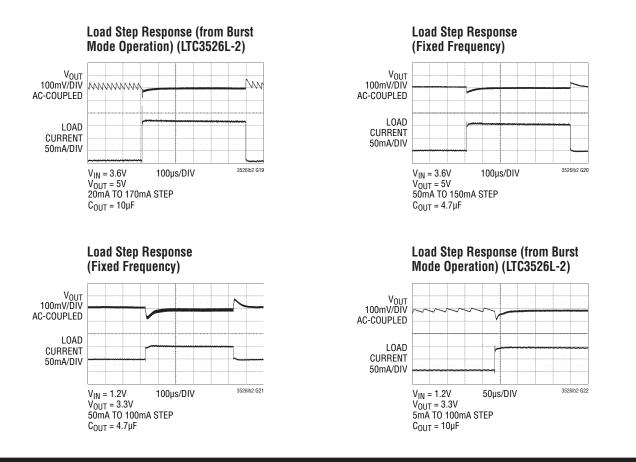


#### VOUT and IIN During Soft-Start



**LINEAR** TECHNOLOGY

### **TYPICAL PERFORMANCE CHARACTERISTICS** $T_A = 25^{\circ}C$ , unless otherwise noted.



### PIN FUNCTIONS

**SW (Pin 1):** Switch Pin. Connect inductor between SW and  $V_{IN}$ . Keep PCB trace lengths as short and wide as possible to reduce EMI. If the inductor current falls to zero or SHDN is low, an internal anti-ringing switch is connected from SW to  $V_{IN}$  to minimize EMI.

**GND (Pin 2, Exposed Pad Pin 7):** Signal and Power Ground. Provide a short direct PCB path between GND and the (-) side of the input and output capacitors. *The Exposed Pad must be soldered to the PCB ground plane*. It serves as an additional ground connection and as a means of conducting heat away from the package.

 $V_{IN}$  (Pin 3): Input Supply Pin. Connect a minimum of 1µF ceramic decoupling capacitor from this pin to ground using short direct PCB traces.

**SHDN (Pin 4):** Logic Controlled Shutdown Input. There is an internal  $4M\Omega$  pull-down on this pin.

- SHDN = High: Normal operation
- $\overline{SHDN}$  = Low: Shutdown, quiescent current < 1µA

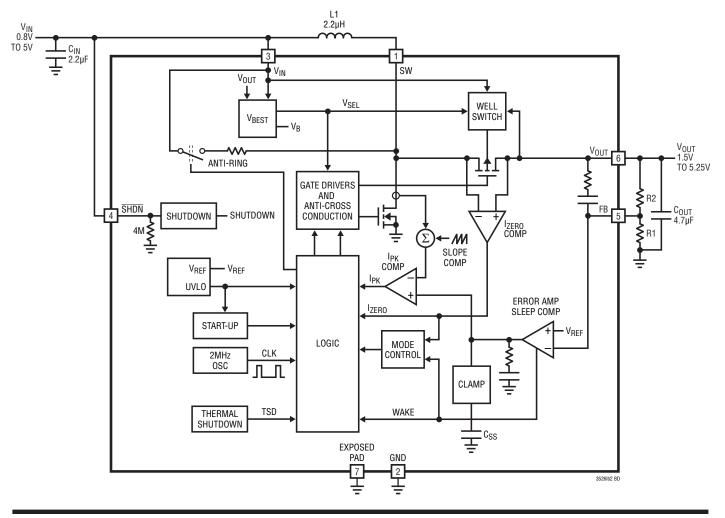
**FB (Pin 5):** Feedback Input to the  $g_m$  Error Amplifier. Connect resistor divider tap to this pin. The top of the divider connects to the output capacitor, the bottom of the divider connects to GND. Referring to the Block Diagram, the output voltage can be adjusted from 1.5V to 5.25V by:

$$V_{\text{OUT}} = 1.195 \text{V} \cdot \left(1 + \frac{\text{R2}}{\text{R1}}\right)$$

 $V_{OUT}$  (Pin 6): Output voltage sense and drain of the internal synchronous rectifier. PCB trace from  $V_{OUT}$  to the output filter capacitor (4.7µF minimum) should be as short and wide as possible.



### **BLOCK DIAGRAM**



### **OPERATION** (Refer to Block Diagram)

The LTC3526L-2/LTC3526LB-2 are 2MHz synchronous boost converters housed in a 6-lead  $2mm \times 2mm$  DFN package. With a guaranteed ability to start up and operate from inputs less than 0.8V, this device features fixed frequency, current mode PWM control for exceptional line and load regulation. The current mode architecture with adaptive slope compensation provides excellent transient load response, requiring minimal output filtering. Internal soft-start and internal loop compensation simplifies the design process while minimizing the number of external components.

With its low  ${\sf R}_{DS(ON)}$  and low gate charge internal N-channel MOSFET switch and P-channel MOSFET synchronous rectifier, the LTC3526L-2 achieves high efficiency over a wide

range of load currents. Burst Mode operation maintains high efficiency at very light loads, reducing the quiescent current to just  $9\mu$ A. Operation can be best understood by referring to the Block Diagram.

#### LOW VOLTAGE START-UP

The LTC3526L-2/LTC3526LB-2 include an independent start-up oscillator designed to start up at an input voltage of 0.68V (typical). Soft-start and inrush current limiting are provided during start-up, as well as normal mode.

When either  $V_{\text{IN}}$  or  $V_{\text{OUT}}$  exceeds 1.3V typical, the IC enters normal operating mode. When the output voltage



### OPERATION (Refer to Block Diagram)

exceeds the input by 0.24V, the IC powers itself from  $V_{OUT}$  instead of  $V_{IN}$ . At this point the internal circuitry has no dependency on the  $V_{IN}$  input voltage, eliminating the requirement for a large input capacitor. The input voltage can drop as low as 0.5V. The limiting factor for the application becomes the availability of the power source to supply sufficient energy to the output at low voltages, and maximum duty cycle, which is clamped at 90% typical. Note that at low input voltages, small voltage drops due to series resistance become critical, and greatly limit the power delivery capability of the converter.

#### LOW NOISE FIXED FREQUENCY OPERATION

#### Soft-Start

The LTC3526L-2/LTC3526LB-2 contain internal circuitry to provide soft-start operation. The soft-start circuitry slowly ramps the peak inductor current from zero to its peak value of 750mA (typical) in approximately 0.5ms, allowing start-up into heavy loads. The soft-start circuitry is reset in the event of a shutdown command or a thermal shutdown.

#### Oscillator

An internal oscillator sets the switching frequency to 2MHz.

#### Shutdown

Shutdown is accomplished by pulling the SHDN pin below 0.3V and enabled by pulling the SHDN pin above 0.8V. Although SHDN can be driven above V<sub>IN</sub> or V<sub>OUT</sub> (up to the absolute maximum rating) without damage, the LTC3526L-2/LTC3526LB-2 have a proprietary test mode that may be engaged if SHDN is held in the range of 0.5V to 1V higher than the greater of V<sub>IN</sub> or V<sub>OUT</sub>. If the test mode is engaged, normal PWM switching action is interrupted, which can cause undesirable operation in some applications. Therefore, in applications where SHDN may be driven above V<sub>IN</sub>, a resistor divider or other means must be employed to keep the SHDN voltage below (V<sub>IN</sub> + 0.4V) to prevent the possibility of the test mode being engaged. Please refer to Figure 1 for two possible implementations.

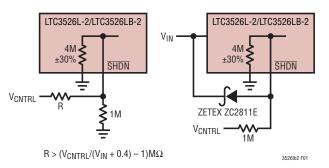


Figure 1. Recommended Shutdown Circuits when Driving SHDN above  $V_{\mbox{\scriptsize IN}}$ 

#### **Error Amplifier**

The positive input of the transconductance error amplifier is internally connected to the 1.195V reference and the negative input is connected to FB. Clamps limit the minimum and maximum error amp output voltage for improved large-signal transient response. Power converter control loop compensation is provided internally. An external resistive voltage divider from  $V_{OUT}$  to ground programs the output voltage via FB from 1.5V to 5.25V.

$$V_{OUT} = 1.195V \cdot \left(1 + \frac{R2}{R1}\right)$$

#### **Current Sensing**

Lossless current sensing converts the peak current signal of the N-channel MOSFET switch into a voltage that is summed with the internal slope compensation. The summed signal is compared to the error amplifier output to provide a peak current control command for the PWM.

#### **Current Limit**

The current limit comparator shuts off the N-channel MOSFET switch once its threshold is reached. The current limit comparator delay to output is typically 60ns. Peak switch current is limited to approximately 750mA, independent of input or output voltage, unless  $V_{OUT}$  falls below 0.7V, in which case the current limit is cut in half.



### **OPERATION** (Refer to Block Diagram)

#### Zero Current Comparator

The zero current comparator monitors the inductor current to the output and shuts off the synchronous rectifier when this current reduces to approximately 30mA. This prevents the inductor current from reversing in polarity, improving efficiency at light loads.

#### Synchronous Rectifier

To control inrush current and to prevent the inductor current from running away when  $V_{OUT}$  is close to  $V_{IN}$ , the P-channel MOSFET synchronous rectifier is only enabled when  $V_{OUT} > (V_{IN} + 0.24V)$ .

#### **Anti-Ringing Control**

The anti-ring circuit connects a resistor across the inductor to prevent high frequency ringing on the SW pin during discontinuous current mode operation. Although the ringing of the resonant circuit formed by L and  $C_{SW}$  (capacitance on SW pin) is low energy, it can cause EMI radiation.

#### **Output Disconnect**

The LTC3526L-2/LTC3526LB-2 are designed to allow true output disconnect by eliminating body diode conduction of the internal P-channel MOSFET rectifier. This allows for  $V_{OUT}$  to go to zero volts during shutdown, drawing no current from the input source. It also allows for inrush current limiting at turn-on, minimizing surge currents seen by the input supply. Note that to obtain the advantages of output disconnect, there must not be an external Schottky diode connected between SW and  $V_{OUT}$ . The output disconnect feature also allows  $V_{OUT}$  to be pulled high, without any reverse current into a battery connected to  $V_{IN}$ .

#### Thermal Shutdown

If the die temperature exceeds 160°C, the LTC3526L-2/ LTC3526LB-2 will go into thermal shutdown. All switches will be off and the soft-start capacitor will be discharged. The device will be enabled again when the die temperature drops by about 15°C.

#### **Burst Mode OPERATION**

The LTC3526L-2 will enter Burst Mode operation at light load current and return to fixed frequency PWM mode when the load increases. Refer to the Typical Performance Characteristics to see the output load Burst Mode threshold current vs  $V_{IN}$ . The load current at which Burst Mode operation is entered can be changed by adjusting the inductor value. Raising the inductor value will lower the load current at which Burst Mode operation is entered.

In Burst Mode operation, the LTC3526L-2 still switches at a fixed frequency of 2MHz, using the same error amplifier and loop compensation for peak current mode control. This control method eliminates any output transient when switching between modes. In Burst Mode operation, energy is delivered to the output until it reaches the nominal regulation value, then the LTC3526L-2 transitions to sleep mode where the outputs are off and the LTC3526L-2 consumes only 9µA of guiescent current from  $V_{OUT}$ . When the output voltage droops slightly, switching resumes. This maximizes efficiency at very light loads by minimizing switching and guiescent losses. Burst Mode output voltage ripple, which is typically 1% peak-to-peak, can be reduced by using more output capacitance (10µF or greater), or with a small capacitor (10pF to 50pF) connected between  $V_{OUT}$  and FB.

As the load current increases, the LTC3526L-2 will automatically leave Burst Mode operation. Note that larger output capacitor values may cause this transition to occur at lighter loads. Once the LTC3526L-2 has left Burst Mode operation and returned to normal operation, it will remain there until the output load is reduced below the burst threshold current.

Burst Mode operation is inhibited during start-up and soft-start and until  $V_{\text{OUT}}$  is at least 0.24V greater than  $V_{\text{IN}}.$ 

The LTC3526LB-2 features continuous PWM operation at 2MHz. At very light loads, the LTC3526LB-2 will exhibit pulse-skipping operation.



### **APPLICATIONS INFORMATION**

#### V<sub>IN</sub> > V<sub>OUT</sub> OPERATION

The LTC3526L-2/LTC3526LB-2 will maintain voltage regulation even when the input voltage is above the desired output voltage. Note that the efficiency is much lower in this mode, and the maximum output current capability will be less. Refer to the Typical Performance Characteristics.

#### SHORT-CIRCUIT PROTECTION

The LTC3526L-2/LTC3526LB-2 output disconnect feature allows output short circuit while maintaining a maximum internally set current limit. To reduce power dissipation under short-circuit conditions, the peak switch current limit is reduced to 400mA (typical).

#### SCHOTTKY DIODE

Although not recommended, adding a Schottky diode from SW to  $V_{OUT}$  will improve efficiency by about 2%. Note that this defeats the output disconnect and short-circuit protection features.

#### PCB LAYOUT GUIDELINES

The high speed operation of the LTC3526L-2/LTC3526LB-2 demands careful attention to board layout. A careless layout will result in reduced performance. Figure 2 shows the recommended component placement. A large ground pin copper area will help to lower the die temperature. A multilayer board with a separate ground plane is ideal, but not absolutely necessary.

#### **COMPONENT SELECTION**

#### **Inductor Selection**

The LTC3526L-2/LTC3526LB-2 can utilize small surface mount chip inductors due to their fast 2MHz switching frequency. Inductor values between  $1.5\mu$ H and  $4.7\mu$ H are suitable for most applications. Larger values of inductance will allow slightly greater output current capability (and lower the Burst Mode threshold) by reducing the inductor ripple current. Increasing the inductance above  $6.8\mu$ H will increase component size while providing little improvement in output current capability.

The minimum inductance value is given by:

$$L > \frac{V_{IN(MIN)} \bullet (V_{OUT(MAX)} - V_{IN(MIN)})}{2 \bullet Ripple \bullet V_{OUT(MAX)}}$$

where:

Ripple = Allowable inductor current ripple (amps peakpeak)

V<sub>IN(MIN)</sub> = Minimum input voltage

V<sub>OUT(MAX)</sub> = Maximum output voltage

The inductor current ripple is typically set for 20% to 40% of the maximum inductor current. High frequency ferrite core inductor materials reduce frequency dependent power losses compared to cheaper powdered iron types, improving efficiency. The inductor should have low ESR (series resistance of the windings) to reduce the I<sup>2</sup>R power losses, and must be able to support the peak

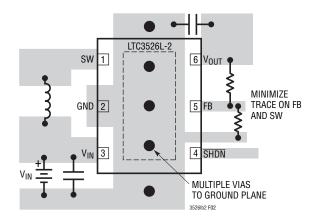


Figure 2. Recommended Component Placement for Single Layer Board





### **APPLICATIONS INFORMATION**

inductor current without saturating. Molded chokes and some chip inductors usually do not have enough core area to support the peak inductor current of 750mA seen on the LTC3526L-2/LTC3526LB-2. To minimize radiated noise, use a shielded inductor. See Table 1 for suggested components and suppliers.

Table 1.	Recommended	Inductors
10010 1.	1100011111011404	maaotoro

VENDOR	PART/STYLE
Coilcraft (847) 639-6400 www.coilcraft.com	LP04815 LPS4012, LPS3314 MSS4020 ME3220
Coiltronics www.cooperet.com	SD10, SD12, SD3114, SD3118
FDK (408) 432-8331 www.fdk.com	MIP3226D MIPF2520D MIPWT3226D MIPSZ2012D MIPS2520D
Murata (714) 852-2001 www.murata.com	LQH3NP LQH32P LQM2MPN
Sumida (847) 956-0666 www.sumida.com	CDRH2D14 CDRH2D11 CDRH3D11
Taiyo-Yuden www.t-yuden.com	NR3010T NR3015T NR3012T
TDK (847) 803-6100 www.component.tdk.com	VLP VLF, VLCF
Toko (408) 432-8282 www.tokoam.com	D412C
Würth (201) 785-8800 www.we-online.com	WE-TPC type S, M, TH, XS

#### **Output and Input Capacitor Selection**

Low ESR (equivalent series resistance) capacitors should be used to minimize the output voltage ripple. Multilayer ceramic capacitors are an excellent choice as they have extremely low ESR and are available in small footprints. A  $4.7\mu$ F to  $10\mu$ F output capacitor is sufficient for most applications. Larger values may be used to obtain extremely low output voltage ripple and improve transient response. X5R and X7R dielectric materials are preferred for their ability to maintain capacitance over wide voltage and temperature ranges. Y5V types should not be used.

The internal loop compensation of the LTC3526L-2/ LTC3526LB-2 are designed to be stable with output capacitor values of 4.7 $\mu$ F or greater (without the need for any external series resistor). Although ceramic capacitors are recommended, low ESR tantalum capacitors may be used as well.

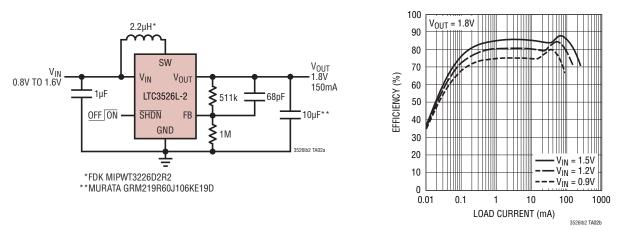
A small ceramic capacitor in parallel with a larger tantalum capacitor may be used in demanding applications that have large load transients. Another method of improving the transient response is to add a small feed-forward capacitor across the top resistor of the feedback divider (from  $V_{OUT}$  to FB). A typical value of 22pF will generally suffice.

Low ESR input capacitors reduce input switching noise and reduce the peak current drawn from the battery. It follows that ceramic capacitors are also a good choice for input decoupling and should be located as close as possible to the device. A  $2.2\mu$ F input capacitor is sufficient for most applications, although larger values may be used without limitations. Table 2 shows a list of several ceramic capacitor manufacturers. Consult the manufacturers directly for detailed information on their selection of ceramic capacitors.

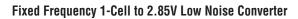
Table 2.	Capacitor	Vendor	Information
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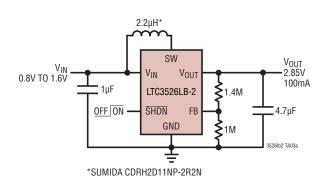
SUPPLIER	PHONE	WEBSITE
AVX	(803) 448-9411	www.avxcorp.com
Murata	(714) 852-2001	www.murata.com
Taiyo-Yuden	(408) 573-4150	www.t-yuden.com
TDK	(847) 803-6100	www.component.tdk.com
Samsung	(408) 544-5200	www.sem.samsung.com

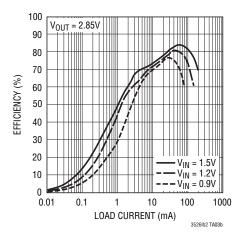
# TYPICAL APPLICATIONS



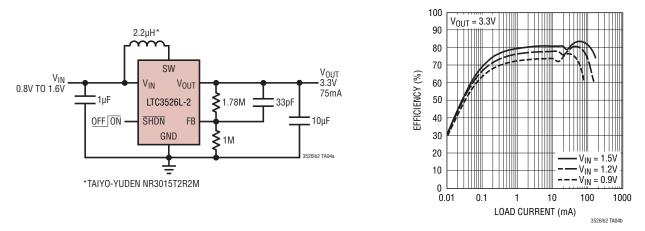
1-Cell to 1.8V Converter with <1mm Maximum Height







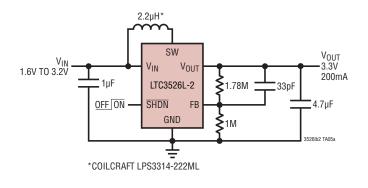


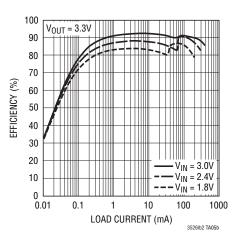




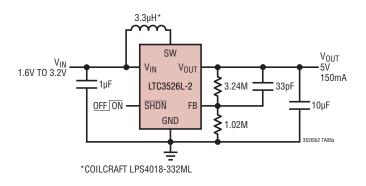
### TYPICAL APPLICATIONS

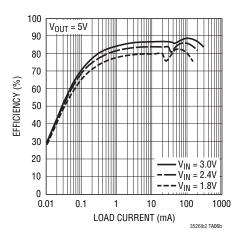
2-Cell to 3.3V



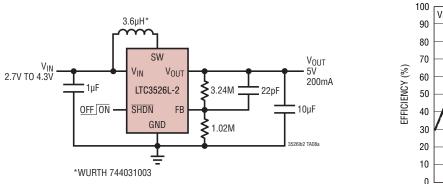


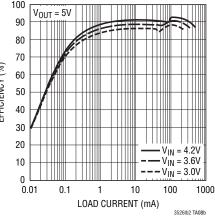
2-Cell to 5V







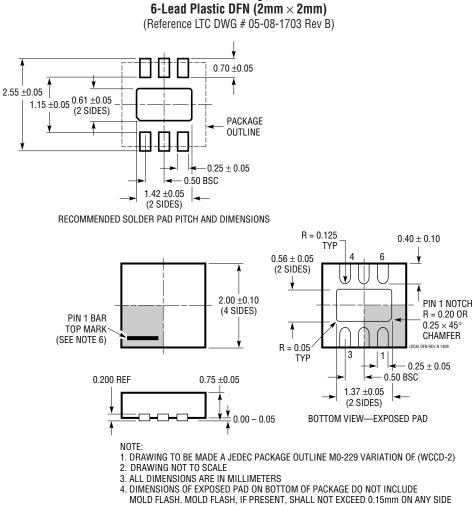




3526lb2fa

13

### PACKAGE DESCRIPTION



**DC Package** 

- MOLD FLASH. MOLD FLASH, IF PRESENT, SHALL NOT EXCEED 0.15mm ON . 5. EXPOSED PAD SHALL BE SOLDER PLATED
- 6. SHADED AREA IS ONLY A REFERENCE FOR PIN 1 LOCATION ON THE
- TOP AND BOTTOM OF PACKAGE



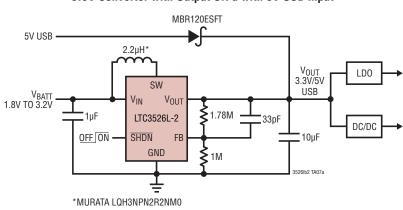
### **REVISION HISTORY**

REV	DATE	DESCRIPTION	PAGE NUMBER
Α	9/10	Changed 60°C/W to 102°C/W in Note 6	3
		Updated Pin 2 text in Pin Functions	6
		Updated Shutdown section	8
		Updated Related Parts	16





### TYPICAL APPLICATION



#### 3.3V Converter with Output OR'd with 5V USB Input

### **RELATED PARTS**

PART NUMBER	DESCRIPTION	COMMENTS
LTC3526/LTC3526B LTC3526-2/LTC3526B-2 LTC3526L/LTC3526LB	500mA, 1MHz/2.2MHz, Synchronous Step-Up DC/DC Converters with Output Disconnect	94% Efficiency $V_{IN}$ : 0.85V to 5V, $V_{OUT(MAX)}$ = 5.25V, $I_Q$ = 9µA, $I_{SD}$ < 1µA, 2mm $\times$ 2mm DFN-6 Package
LTC3525L-3	400mA Micropower Synchronous Step-Up DC/DC Converter with Output Disconnect	93% Efficiency $V_{IN}$ : 0.88V to 4.5V, $V_{OUT}$ = 3V, $I_Q$ = 7µA, $I_{SD}$ < 1µA, SC-70 Package
LTC3525-3 LTC3525-3.3 LTC3525-5	400mA Micropower Synchronous Step-Up DC/DC Converter with Output Disconnect	95% Efficiency V <sub>IN</sub> : 1V to 4.5V, V <sub>OUT(MAX)</sub> = 3.3V or 5V, I <sub>Q</sub> = 7µA, I <sub>SD</sub> < 1µA, SC-70 Package
LTC3427	500mA I <sub>SW</sub> , 1.2MHZ, Synchronous Step-Up DC/DC Converter with Output Disconnect	93% Efficiency V <sub>IN</sub> : 1.8V to 4.5V, V <sub>OUT(MAX)</sub> = 5V, 2mm $\times$ 2mm DFN Package
LTC3400/LTC3400B	600mA I <sub>SW</sub> , 1.2MHz, Synchronous Step-Up DC/DC Converters	92% Efficiency V <sub>IN</sub> : 1V to 5V, V <sub>OUT(MAX)</sub> = 5V, I <sub>Q</sub> = 19µA/300µA, I <sub>SD</sub> < 1µA, ThinSOT™ Package
LTC3527/LTC3527-1	Dual 600mA/400mA I <sub>SW</sub> , 1.2MHz/2.2MHz Synchronous Step-Up DC/DC Converters	94% Efficiency $V_{IN}$ : 0.7V to 5V, $V_{OUT(MAX)}$ = 5.25V, $I_Q$ = 12µA, $I_{SD} <$ 1µA, 3mm $\times$ 3mm QFN-16 Package



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